



RECEIVED

MAR 08 2004

Sheet 1 of 1

Form 1449	Atty. Docket No.: 303.776US1	Serial No. 09/945,495
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)	Applicant: Fernando Gonzalez	
	Filing Date: August 30, 2001	Group: 2811

U.S. PATENT DOCUMENTS

**Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
-----------------------	-----------------	------	------	-------	----------	-------------------------------

FOREIGN PATENT DOCUMENTS

**Examiner Initial	Document Number	Date	Country	Class	Subclass	Translation Yes No
-----------------------	-----------------	------	---------	-------	----------	-------------------------

OTHER DOCUMENTS

(Including Author, Title, Date, Pertinent Pages, Etc.)

**Examiner Initial	
OKO	Chang, C., et al., "Enabling Shallow Trench isolation for .01 micrometer Technologies and Beyond", <u>Symposium on VLSI Technology Digest of Technical Papers</u> , pp. 161-162, (1999)
OKO	Goebel, B., et al., "Vertical N-Channel MOSFETs for Extremely High Density Memories: The Impact of Interface Orientation on Device Performance", <u>IEEE Transactions on Electron Devices</u> , 48(5), pp. 897-906, (May 2001)
OKO	Matsuda, S., et al., "Novel Corner Rounding Process for Shallow Trench Isolation utilizing MSTs (Micro-Structure Transformation of Silicon)", <u>IEDM</u> , pp. 137-140, (1998)
OKO	Uh, H., et al., "A Strategy for Long Data Retention Time of 512Mb DRAM with 0.12micrometer Design Rule", <u>Symposium on VLSI Technology Digests of Technical Papers</u> , 2 pages, (2001)

Examiner <u>Don E. Omer</u>	Date Considered <u>3/22/04</u>
-----------------------------	--------------------------------

*Substitute Disclosure Statement Form (PTO-1449)

**EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.